Bulletin I0114J 05/00



FAST RECOVERY DIODES

■ Junction Size: Rectangular 350 x 230 mils

■ Wafer Size:

1000 to 1200 V ■ V_{RRM} Class:

Glassivated MOAT Passivation Process:

■ Reference IR Packaged Part: 60EPF Series

Major Ratings and Characteristics

Parameters		Units	Test Conditions
V _{FM}	Maximum Forward Voltage	1300 mV	$T_J = 25$ °C, $I_F = 60$ A
V _{RRN}	Reverse Breakdown Voltage Range	1000 to 1200 V	$T_J = 25^{\circ}C, I_{RRM} = 100 \mu A$ (1)

⁽¹⁾ Nitrogen flow on die edge.

Mechanical Characteristics

Nominal Back Metal Composition, Thickness	Cr-Ni-Ag (1 KA-4 KA-6 KA)
Nominal Front Metal Composition, Thickness	100% AI, (20 µm)
Chip Dimensions	350 x 230 mils (8.89x5.84 mm) - see drawing
WaferDiameter	100 mm, with std. < 110 > flat
WaferThickness	260 µm
Maximum Width of Sawing Line	45 µm
Reject Ink Dot Size	0.25 mm diameter minimum
InkDotLocation	Seedrawing
Recommended Storage Environment	Storage in original container, in dessicated nitrogen, with no contamination

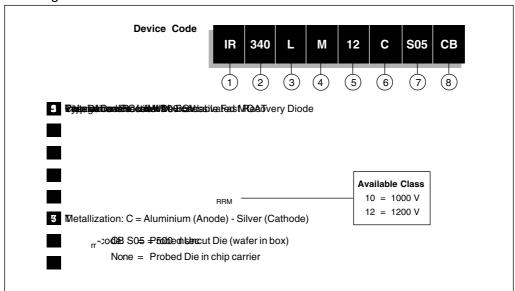
IR340LM..CS05CB Series

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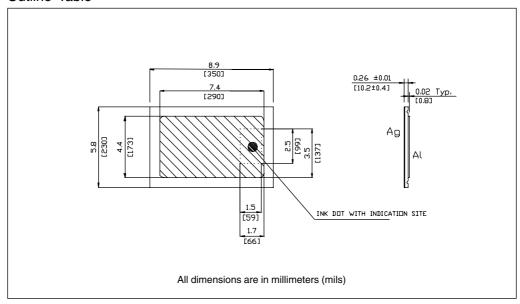
International

TOR Rectifier

Ordering Information Table



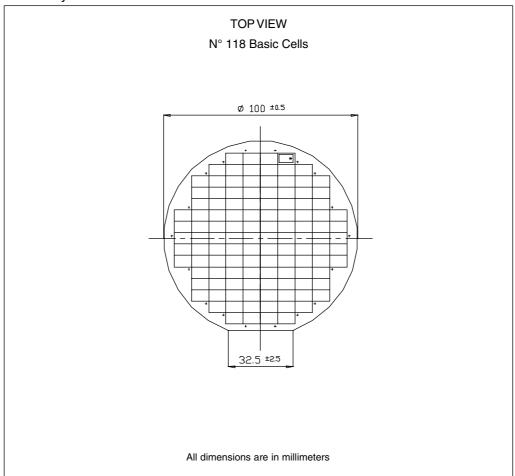
Outline Table



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Wafer Layout





Vishay

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